

Electronic Supplementary Data

Computational Study of Crystallography, Defects, Ion Migration and Dopants in Almandine Garnet

Janya Lumbini Subasinghe¹, Sashikesh Ganeshalingam¹ and Navaratnarajah Kuganathan^{2,*}

¹ Department of Chemistry, University of Jaffna, Sir. Pon Ramanathan Road, Thirunelvely, Jaffna, 40000, Srilanka.

² Department of Materials, Faculty of Engineering, Imperial College London, London, SW7 2AZ, United Kingdom.

*Correspondence: n.kuganathan@imperial.ac.uk

Table S1. Two body Buckingham potentials used for dopant oxides in Fe₂Al₂Si₃O₁₂.

Interaction	<i>A</i> (eV)	ρ (Å)	<i>C</i> (eV·Å ⁶)	<i>Y</i> (e)	<i>K</i> (eV·Å ⁻²)
Ni ²⁺ - O ²⁻	683.5	0.3332	0.000	2.000	8.77
Co ²⁺ - O ²⁻	696.3	0.3362	0.000	2.000	10.74
Zn ²⁺ - O ²⁻	499.6	0.3595	0.000	2.050	10.28
Mn ²⁺ - O ²⁻	715.80	0.3464	0.000	3.000	81.20
Mg ²⁺ - O ²⁻	946.627	0.31813	0.000	2.000	99999
Ca ²⁺ - O ²⁻	1090.40	0.3372	0.000	1.260	34.00
Sr ²⁺ - O ²⁻	776.84	0.35867	0.000	1.526	11.406
Ba ²⁺ - O ²⁻	931.79	0.3949	0.000	1.460	14.78
Ga ³⁺ - O ²⁻	2901.12	0.2742	0.000	1.000	99999
Sc ³⁺ - O ²⁻	1575.85	0.3211	0.000	3.000	99999
In ³⁺ - O ²⁻	1495.65	0.3327	4.33	3.000	99999
Y ³⁺ - O ²⁻	1345.10	0.3491	0.00	3.000	99999
Gd ³⁺ - O ²⁻	1885.75	0.3399	20.34	3.000	99999
La ³⁺ - O ²⁻	1545.21	0.3590	0.00	-0.250	145.0
Ge ⁴⁺ - O ²⁻	1497.3996	0.325646	16.00	4.000	99999
Sn ⁴⁺ - O ²⁻	1414.32	0.3479	13.66	4.000	99999
Ti ⁴⁺ - O ²⁻	877.20	0.38096	9.00	-35.8630	65974.00
Zr ⁴⁺ - O ²⁻	1502.11	0.3477	0.00	1.35	169.617
Ce ⁴⁺ - O ²⁻	1986.83	0.3511	20.40	7.70	291.75